

INCHANGE SEMICONDUCTOR

isc Silicon NPN Power Transistor

2N6130

DESCRIPTION

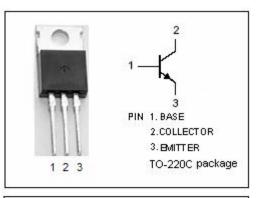
- DC Current Gain-
- : h_{FE} = 20-100@ I_C= 2.5A
- Collector-Emitter Sustaining Voltage-
- : V_{CEO(SUS)} = 60V(Min)
- Complement to Type 2N6133
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

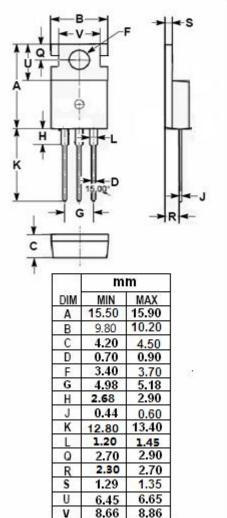
ABSOLUTE MAYIMUM PATINGS/T. -25m

APPLICATIONS

• Designed for use in power amplifier and switching circuits applications

SYMBOL	PARAMETER	VALUE	UNIT	
Vсво	Collector-Base Voltage	60	V	
V _{CEO}	Collector-Emitter Voltage	60	V	
V _{EBO}	Emitter-Base Voltage	5	V	
lc	Collector Current-Continuous	7	A	
I _B	Base Current	2	A	
Pc	Collector Power Dissipation $T_c=25^{\circ}C$	50	W	
Tj	Junction Temperature	150	ĉ	
T _{stg}	Storage Temperature Range	-65~150	°C	





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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
Vceo(sus)	Collector-Emitter Sustaining Voltage	I _C = 30mA; I _B = 0	60		V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 7A; I _B = 1.4A		1.4	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 7A; V _{CE} = 4V		3.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 60V; I _E = 0		0.1	mA
I _{CEO}	Collector Cutoff Current	V _{CE} = 60V; I _B = 0		1.0	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		1.0	mA
h _{FE-1}	DC Current Gain	I _C = 2.5A ; V _{CE} = 4V	20	100	
h _{FE-2}	DC Current Gain	I _C = 7A ; V _{CE} = 4V	5		
f⊤	Current-Gain—Bandwidth Product	Ic= 0.5A ; V _{CE} = 4V	2.5		MHz

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